IGBT with Monolithic Free Wheeling Diode

This Insulated Gate Bipolar Transistor (IGBT) features a robust and cost effective Field Stop (FS) Trench construction, and provides superior performance in demanding switching applications, offering both low on–state voltage and minimal switching loss. The IGBT is well suited for resonant or soft switching applications.

Features

- Extremely Efficient Trench with Fieldstop Technology
- 1350 V Breakdown Voltage
- Optimized for Low Losses in IH Cooker Application
- Reliable and Cost Effective Single Die Solution
- These are Pb–Free Devices

Typical Applications

- Inductive Heating
- Consumer Appliances
- Soft Switching

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-emitter voltage	V _{CES}	1350	V
Collector current @ Tc = 25°C @ Tc = 100°C	Ι _c	80 40	A
Pulsed collector current, T _{pulse} limited by T _{Jmax} , 10 μ s Pulse, V _{GE} = 15 V	I _{CM}	120	A
Diode forward current @ Tc = 25°C @ Tc = 100°C	I _F	80 40	A
Diode pulsed current, T_{pulse} limited by T_{Jmax} , 10 μs Pulse, V_{GE} = 0 V	I _{FM}	120	A
Gate-emitter voltage Transient Gate-emitter Voltage ($T_{pulse} = 5 \ \mu s, D < 0.10$)	V_{GE}	±20 ±25	V
Power Dissipation @ Tc = 25°C @ Tc = 100°C	P _D	394 197	W
Operating junction temperature range	ТJ	-40 to +175	°C
Storage temperature range	T _{stg}	–55 to +175	°C
Lead temperature for soldering, 1/8" from case for 5 seconds	T _{SLD}	260	°C

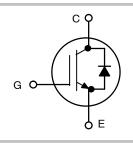
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

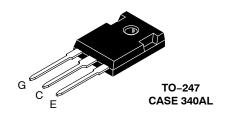


ON Semiconductor®

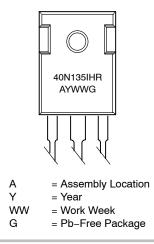
http://onsemi.com

40 A, 1350 V V_{CEsat} = 2.40 V E_{off} = 1.30 mJ





MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping
NGTB40N135IHRWG	TO–247 (Pb–Free)	30 Units / Rail

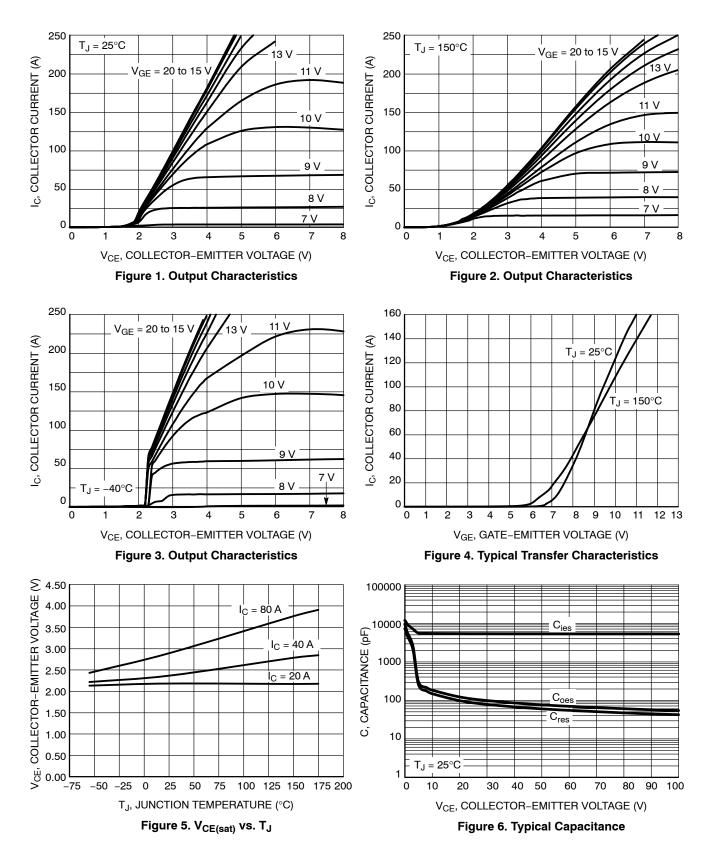
THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal resistance junction-to-case	$R_{ ext{ heta}JC}$	0.385	°C/W
Thermal resistance junction-to-ambient	$R_{\theta JA}$	40	°C/W

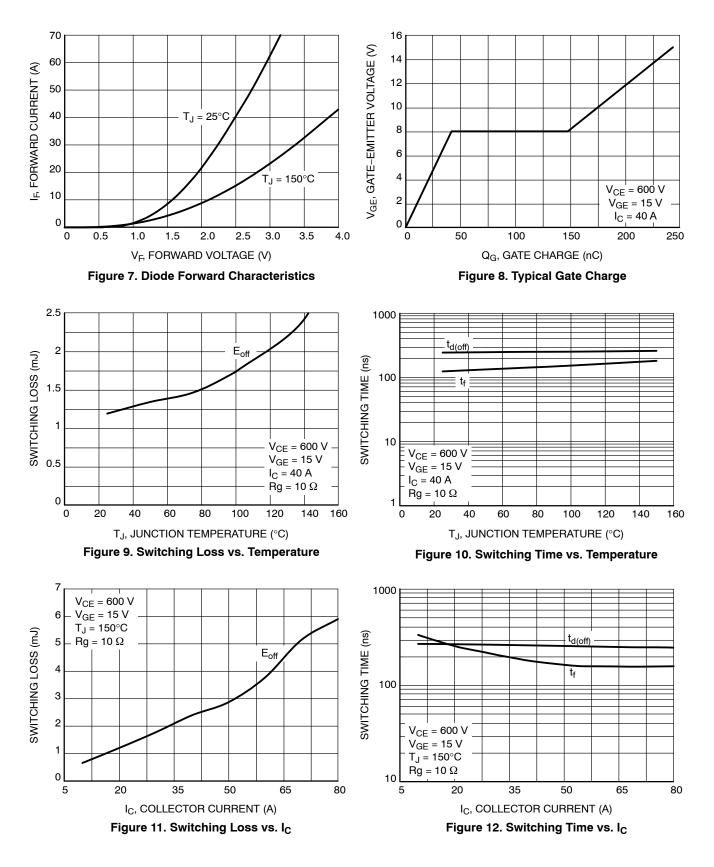
ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
STATIC CHARACTERISTIC	•	•		•		
Collector-emitter breakdown voltage, gate-emitter short-circuited	V_{GE} = 0 V, I _C = 500 μ A	V _{(BR)CES}	1350	_	_	V
Collector-emitter saturation voltage	V_{GE} = 15 V, I _C = 40 A V _{GE} = 15 V, I _C = 40 A, T _J = 175°C	V _{CEsat}	-	2.40 2.80	2.70 -	V
Gate-emitter threshold voltage	$V_{GE} = V_{CE}$, $I_C = 250 \ \mu A$	V _{GE(th)}	4.5	5.5	6.5	V
Collector-emitter cut-off current, gate- emitter short-circuited	$V_{GE} = 0 V, V_{CE} = 1350 V$ $V_{GE} = 0 V, V_{CE} = 1350 V, T_{J} = 175^{\circ}C$	I _{CES}	_	_ _	0.5 2.0	mA
Gate leakage current, collector-emitter short-circuited	V_{GE} = 20 V, V_{CE} = 0 V	I _{GES}	_	-	100	nA
DYNAMIC CHARACTERISTIC	•	•				
Input capacitance	V _{CE} = 20 V, V _{GE} = 0 V, f = 1 MHz	C _{ies}	-	5290	_	pF
Output capacitance		C _{oes}	-	124	-	
Reverse transfer capacitance		C _{res}	-	100	-	
Gate charge total		Qg	-	234	-	nC
Gate to emitter charge	V_{CE} = 600 V, I _C = 40 A, V _{GE} = 15 V	Q _{ge}	-	39	-	
Gate to collector charge		Q _{gc}	-	105	-	
SWITCHING CHARACTERISTIC, INDUCT						
Turn-off delay time	$\begin{array}{c} {T_{\rm J}} = 25^{\circ}{\rm C} \\ {V_{\rm CC}} = 600 \; {\rm V}, {I_{\rm C}} = 40 \; {\rm A} \\ {R_{\rm g}} = 10 \; {\Omega} \\ {V_{\rm GE}} = 0 \; {\rm V}/ \; 15 \; {\rm V} \end{array}$	t _{d(off)}	-	250	-	ns
Fall time		t _f	-	130	-	
Turn-off switching loss		E _{off}	-	1.30	-	mJ
Turn-off delay time	$\begin{array}{c} T_{J} = 150^{\circ}C \\ V_{CC} = 600 \text{ V, } I_{C} = 40 \text{ A} \\ R_{g} = 10 \Omega \\ V_{GE} = 0 \text{ V/ } 15 \text{ V} \end{array}$	t _{d(off)}	-	260	-	ns
Fall time		t _f	-	190	-	
Turn-off switching loss		E _{off}	-	2.60	-	mJ
DIODE CHARACTERISTIC						
Forward voltage	V _{GE} = 0 V, I _F = 40 A V _{GE} = 0 V, I _F = 40 A, T _J = 175°C	V _F		2.30 3.70	2.70	V

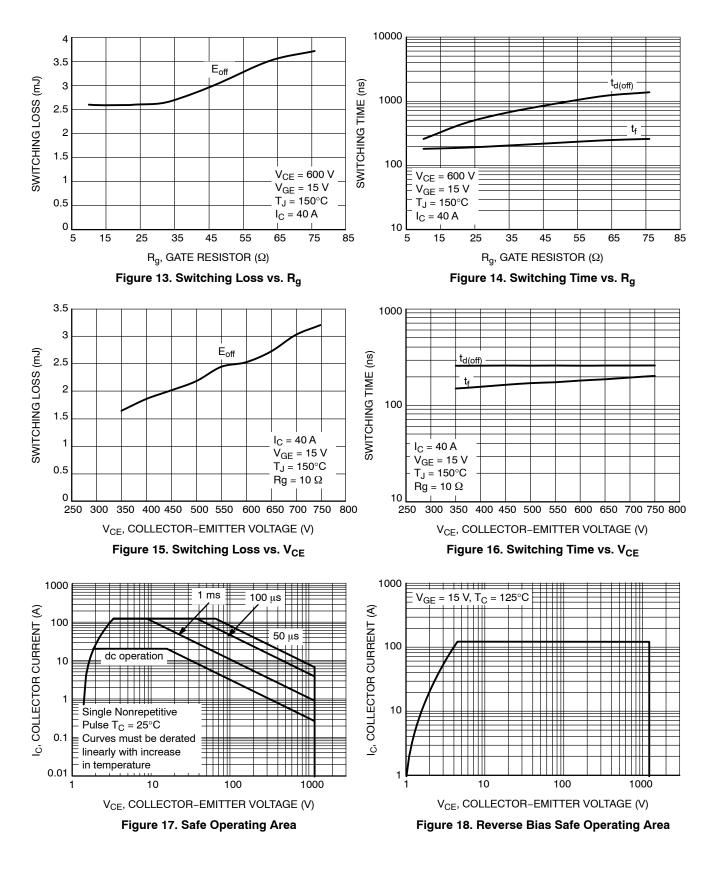
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

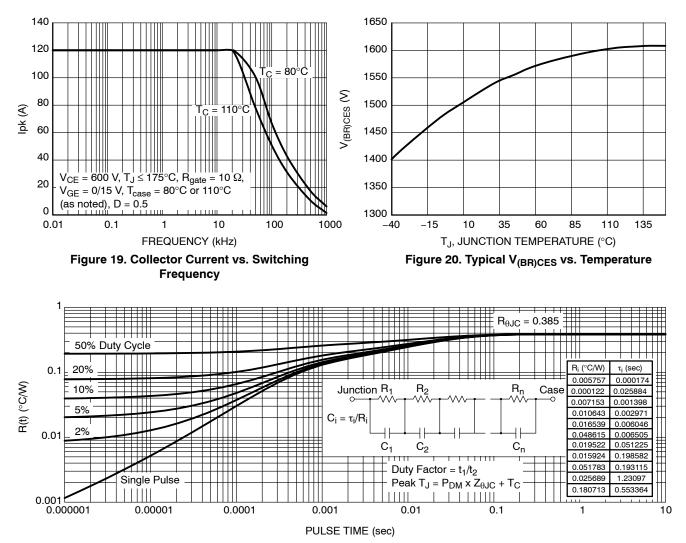


Figure 21. IGBT Transient Thermal Impedance

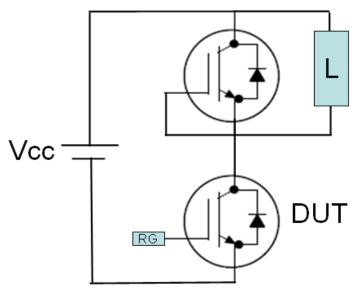
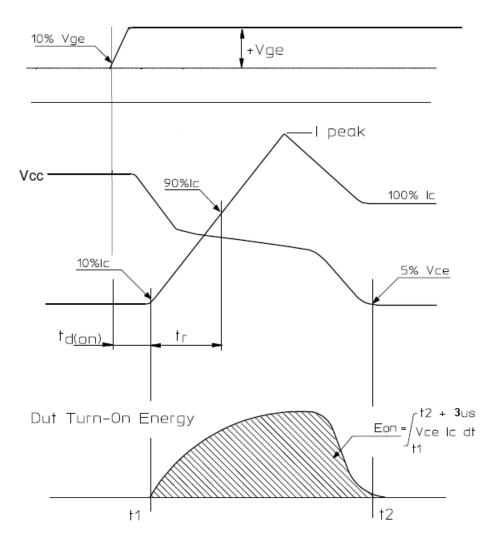
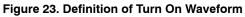


Figure 22. Test Circuit for Switching Characteristics





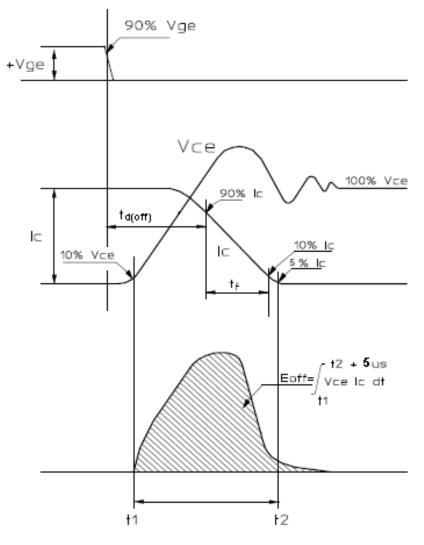
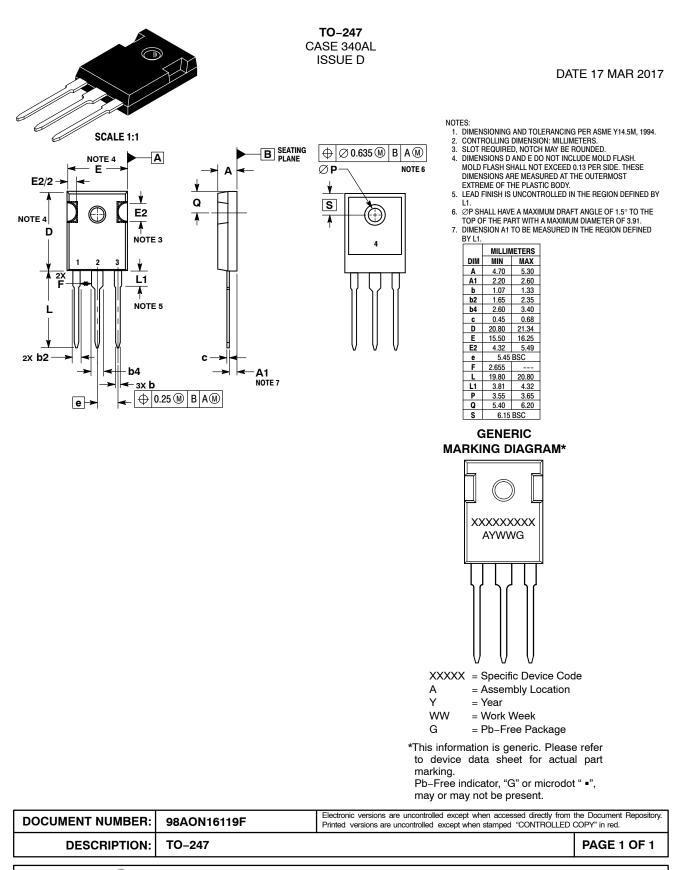


Figure 24. Definition of Turn Off Waveform

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS





ON Semiconductor and use trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

٥